NSN 5961-01-215-8751

Diode Semiconductor Device - Page 1 of 1



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Overall Height:
0.200 inches
Overall Diameter:
0.330 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
50.0 repetitive peak reverse voltage and 35.0 reverse voltage, total rms
Current Rating Per Characteristic:
17.00 amperes forward current, average pascal
Maximum Operating Tempurature Per Measurement Point:
125.0 degrees celsius junction
Terminal Type And Quantity:
4 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0